Non-Inverting 3-State Buffer

The NL17SZ125 is a high performance non-inverting buffer operating from a 1.65 V to 5.5 V supply.

- Extremely High Speed: t_{PD} 2.6 ns (typical) at $V_{CC} = 5.0 \text{ V}$
- Designed for 1.65 V to 5.5 V V_{CC} Operation
- Overvoltage Tolerant Inputs and Outputs
- LVTTL Compatible Interface Capability With 5.0 V TTL Logic with $V_{CC} = 3.0 \text{ V}$
- LVCMOS Compatible
- 24 mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current Substantially Reduces System Power Requirements
- 3-State OE Input is Active-Low
- Replacement for NC7SZ125
- Chip Complexity = 36 FETs
- Pb-Free Package is Available

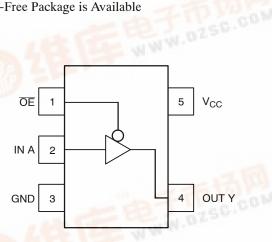


Figure 1. Pinout (Top View)

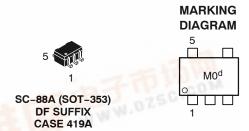


WWW.DZSC.COM Figure 2. Logic Symbol



ON Semiconductor®

http://onsemi.com



d = Date Code

PIN ASSIGNMENT					
1	ŌE				
2	IN A				
3	GND				
4	OUT Y				
5	Vcc				

FUNCTION TABLE

OE Input	A Input	Y Output
L	L	L
L	Н	Н
Н	Х	Z
X = Don't Care	由子市	MOD.DO

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.



MAXIMUM RATINGS

Symbol	Parameter		Value	Unit
V _{CC}	DC Supply Voltage		-0.5 to +7.0	V
V _{IN}	DC Input Voltage		-0.5 to +7.0	V
V _{OUT}	DC Output Voltage		-0.5 to +7.0	V
I _{IK}	DC Input Diode Current		-50	mA
I _{OK}	DC Output Diode Current		-50	mA
I _{OUT}	DC Output Sink Current		±50	mA
I _{CC}	DC Supply Current per Supply Pin		±100	mA
T _{STG}	Storage Temperature Range		−65 to +150	°C
TL	Lead Temperature, 1 mm from Case for 10 Seconds		260	°C
TJ	Junction Temperature Under Bias		+ 150	°C
θ_{JA}	Thermal Resistance (Note 1)		350	°C/W
P_{D}	Power Dissipation in Still Air at 85°C		150	mW
MSL	Moisture Sensitivity		Level 1	
F _R	Flammability Rating Oxyg	gen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
V _{ESD}	Mach	ody Model (Note 2) ine Model (Note 3) rice Model (Note 4)	> 2000 > 200 N/A	V

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

- 1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2 ounce copper trace with no air flow.
- 2. Tested to EIA/JESD22-A114-A.
- 3. Tested to EIA/JESD22-A115-A.
- 4. Tested to JESD22-C101-A.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Max	Unit
V _{CC}	DC Supply Voltage		1.65	5.5	V
V _{IN}	DC Input Voltage		0	5.5	V
V _{OUT}	DC Output Voltage		0	5.5	٧
T _A	Operating Temperature Range		-40	+125	°C
t _r , t _f	V _{CC} = 2	8 V ±0.15 V 2.5 V ±0.2 V 3.0 V ±0.3 V 5.0 V ±0.5 V	0 0 0 0	20 20 10 5.0	ns/V

DEVICE JUNCTION TEMPERATURE VERSUS TIME TO 0.1% BOND FAILURES

Junction Temperature °C	Time, Hours	Time, Years
80	1,032,200	117.8
90	419,300	47.9
100	178,700	20.4
110	79,600	9.4
120	37,000	4.2
130	17,800	2.0
140	8,900	1.0

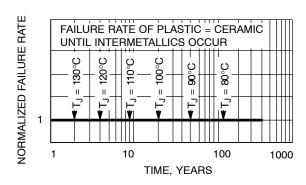


Figure 3. Failure Rate vs. Time Junction Temperature

DC ELECTRICAL CHARACTERISTICS

		V _{CC}	T,	_Δ = 25°(C	-40°C ≤ T	A ≤ 125°C		
Symbol	Parameter	(V)	Min	Тур	Max	Min	Max	Unit	Condition
V _{IH}	High-Level Input Voltage	1.65 to 1.95 2.3 to 5.5	0.75 V _{CC} 0.7 V _{CC}			0.75 V _{CC} 0.7 V _{CC}		V	
V _{IL}	Low-Level Input Voltage	1.65 to 1.95 2.3 to 5.5			0.25 V _{CC} 0.3 V _{CC}		0.25 V _{CC} 0.3 V _{CC}	٧	
V _{OH}	High-Level Output Voltage V _{IN} = V _{IH}	1.65 1.8 2.3 3.0 4.5	1.55 1.7 2.2 2.9 4.4	1.65 1.8 2.3 3.0 4.5		1.55 1.7 2.2 2.9 4.4		V	I _{OH} = -100 μA
		1.65 2.3 3.0 3.0 4.5	1.29 1.9 2.4 2.3 3.8	1.52 2.15 2.80 2.68 4.20		1.29 1.9 2.4 2.3 3.8		V	I _{OH} = -4 mA I _{OH} = -8 mA I _{OH} = -16 mA I _{OH} = -24 mA I _{OH} = -32 mA
V _{OL}	Low-Level Output Voltage V _{IN} = V _{IL}	1.65 1.8 2.3 3.0 4.5		0.0 0.0 0.0 0.0 0.0	0.1 0.1 0.1 0.1 0.1		0.1 0.1 0.1 0.1 0.1	V	I _{OL} = 100 μA
		1.65 2.3 3.0 3.0 4.5		0.08 0.10 0.15 0.22 0.22	0.24 0.30 0.40 0.55 0.55		0.24 0.30 0.40 0.55 0.55	V	I _{OL} = 4 mA I _{OL} = 8 mA I _{OL} = 16 mA I _{OL} = 24 mA I _{OL} = 32 mA
I _{IN}	Input Leakage Current	0 to 5.5			±1.0		±1.0	μΑ	$0 \text{ V} \leq \text{V}_{\text{IN}} \leq 5.5 \text{ V}$
I _{OZ}	3-State Output Leakage	1.65 to 5.5			± 0.5		±5.0	μΑ	$V_{IN} = V_{IH} \text{ or } V_{IL}$ 0 V \leq V _{OUT} \leq 5.5 V
I _{OFF}	Power Off Leakage Current	0.0			1.0		10	μΑ	V _{IN} or V _{OUT} = 5.5 V
I _{CC}	Quiescent Supply Current	1.65 to 5.5			1.0		10	μΑ	V _{IN} = 5.5 V, GND

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AC ELECTRICAL CHARACTERISTICS ($t_R = t_F = 3.0 \text{ ns}$)

				Vcc	T _A = 25°C			-40°C ≤ T	A ≤ 125°C	
Symbol	Parameter	Condi	tion	(V)	Min	Тур	Max	Min	Max	Unit
t _{PLH}	Propagation Delay	$R_L = 1 M\Omega$	C _L = 15 pF	1.8 ± 0.15	2.0	9.0	10	2.0	10.5	ns
t _{PHL}	AN to YN (Figures 4 and 5, Table 1)	R _L = 1 MΩ	C _L = 15 pF	2.5 ± 0.2	1.0		7.5	1.0	8.0	
		$R_L = 1 \text{ M}\Omega$ $R_L = 500 \Omega$	C _L = 15 pF C _L = 50 pF	3.3 ± 0.3	0.8 1.2		5.2 5.7	0.8 1.2	5.5 6.0	
		$\begin{aligned} R_L &= 1 \ M\Omega \\ R_L &= 500 \ \Omega \end{aligned}$	C _L = 15 pF C _L = 50 pF	5.0 ± 0.5	0.5 0.8		4.5 5.0	0.5 0.8	4.8 5.3	
t _{PZH}	Output Enable Time	$R_L = 250 \Omega$	C _L = 50 pF	1.8 ± 0.15	2.0	7.6	9.5	2.0	10	ns
t_{PZL}	(Figures 6, 7and 8, Table 1)			2.5 ± 0.2	1.8		8.5	1.8	9.0]
				3.3 ± 0.3	1.2		6.2	1.2	6.5	
				5.0 ± 0.5	0.8		5.5	0.8	5.8]
t _{PHZ}	Output Disable Time	R _L and R ₁ = 500	Ω C _L = 50 pF	1.8 ± 0.15	2.0	8.0	10	2.0	10.5	ns
t_{PLZ}	(Figures 6, 7and 8, Table 1)			2.5 ± 0.2	1.5		8.0	1.5	8.5	
				3.3 ± 0.3	0.8		5.7	0.8	6.0	
				5.0 ± 0.5	0.3		4.7	0.3	5.0	

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Condition	Typical	Unit
C _{IN}	Input Capacitance	$V_{CC} = 5.5 \text{ V}, V_I = 0 \text{ V or } V_{CC}$	2.5	pF
C _{OUT}	Output Capacitance	$V_{CC} = 5.5 \text{ V}, V_I = 0 \text{ V or } V_{CC}$	2.5	pF
C _{PD}	Power Dissipation Capacitance (Note 5)	10 MHz, V _{CC} = 3.3 V, V _I = 0 V or V _{CC} 10 MHz, V _{CC} = 5.5 V, V _I = 0 V or V _{CC}	9 11	pF

^{5.} C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC(OPR)} = C_{PD} • V_{CC} • f_{in} + I_{CC}. C_{PD} is used to determine the no–load dynamic power consumption; P_D = C_{PD} • V_{CC}² • f_{in} + I_{CC} • V_{CC}.

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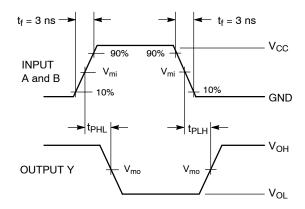
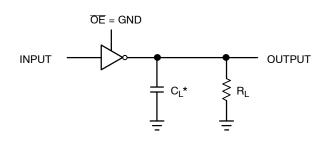


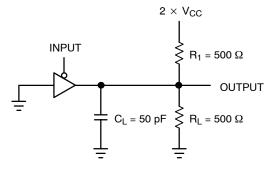
Figure 4. Switching Waveform



*Includes all probe and jig capacitance.

A 1 MHz square input wave is recommended for propagation delay tests.

Figure 5. T_{PLH} or T_{PHL}



A 1 MHz square input wave is recommended for propagation delay tests.

V_{CC} OUTPUT $C_{L} = 50 \text{ pF}$ $R_{L} = 250 \Omega$

A 1 MHz square input wave is recommended for propagation delay tests.

Figure 6. T_{PZL} or T_{PL}

Figure 7. T_{PZH} or T_{PHZ}

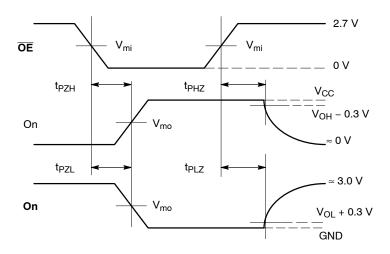


Figure 8. AC Output Enable and Disable Waveform

Table 1. Output Enable and Disable Times

 $t_R = t_F = 2.5 \text{ ns}, 10\% \text{ to } 90\%; f = 1 \text{ MHz}; t_W = 500 \text{ ns}$

	V _{CC}						
Symbol	3.3 V ± 0.3 V	2.7 V	2.5 V ± 0.2 V				
V_{mi}	1.5 V	1.5 V	V _{CC/} 2				
V_{mo}	1.5 V	1.5 V	V _{CC/} 2				

DEVICE ORDERING INFORMATION

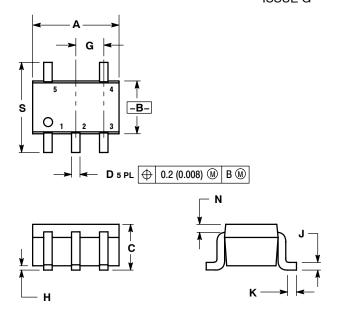
			Dev	rice Nomenclati	ure				Shipping [†]	
Device	Logic Circuit Indicator	No. of Gates per Package	Temp Range Identifier	Technology	Device Function	Package Suffix	Tape and Reel Suffix	Package		
NL17SZ125DFT2	NL	1	7	SZ	125	DF	T2	SC-88A (SOT-353)	3000 / Tape & Reel 178 mm (7")	
NL17SZ125DFT2G	NL	1	7	SZ	125	DF	T2G	SC-88A (SOT-353) (Pb-Free)	3000 / Tape & Reel 178 mm (7")	

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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PACKAGE DIMENSIONS

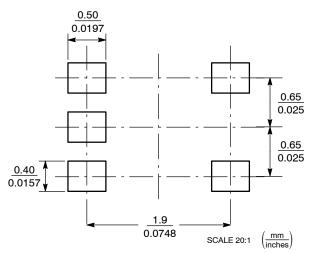
SC-88A (SOT-353) DF SUFFIX CASE 419A-02 ISSUE G



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. 419A-01 OBSOLETE. NEW STANDARD 419A-02.
 4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.071	0.087	1.80	2.20	
В	0.045	0.053	1.15	1.35	
С	0.031	0.043	0.80	1.10	
D	0.004	0.012	0.10	0.30	
G	0.026	BSC	0.65 BSC		
Н		0.004		0.10	
J	0.004	0.010	0.10	0.25	
K	0.004	0.012	0.10	0.30	
N	0.008	REF	0.20	REF	
S	0.079	0.087	2.00	2.20	

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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